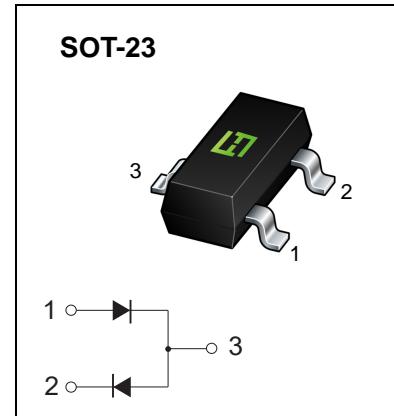
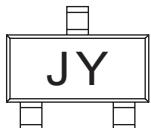


FEATURES

- This Switching Diode has The Following Features:
- Low Leakage Current Applications

Marking: JY



Maximum Ratings @Ta=25°C

Parameter	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	85	V
Continuous Reverse Voltage	V _R	85	V
Continuous Forward Current Single Diode Double Diode	I _F	160 140	mA
Repetitive Peak Forward Current	I _{FRM}	500	mA
Non-Repetitive Peak Forward Surge Current at t = 1 μs at t = 1 ms at t = 1 s	I _{FSM}	4 1 0.5	A
Power Dissipation	P _D	250	mW
Thermal Resistance Junction to Ambient Air	R _{θJA}	500	°C/W
Operating and Storage Temperature Range	T _j , T _{stg}	- 65 to + 150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage at I _R = 100 μA	V _{(BR)R}	85	-	-	V
Forward Voltage at I _F = 1 mA at I _F = 10 mA at I _F = 50 mA at I _F = 150 mA	V _F	- - - -	- - - -	0.9 1 1.1 1.25	V
Reverse Current at V _R = 75 V at V _R = 75 V, T _j = 150 °C	I _R I _R	- -	- -	5 80	nA
Total Capacitance at V _R = 0, f = 1 MHz	C _T	-	2	-	pF
Reverse Recovery Time at I _F = I _R = 10 mA, I _{rr} = 0.1 X I _R , R _L = 100 Ω	t _{rr}	-	-	3	μs

Typical Characteristics

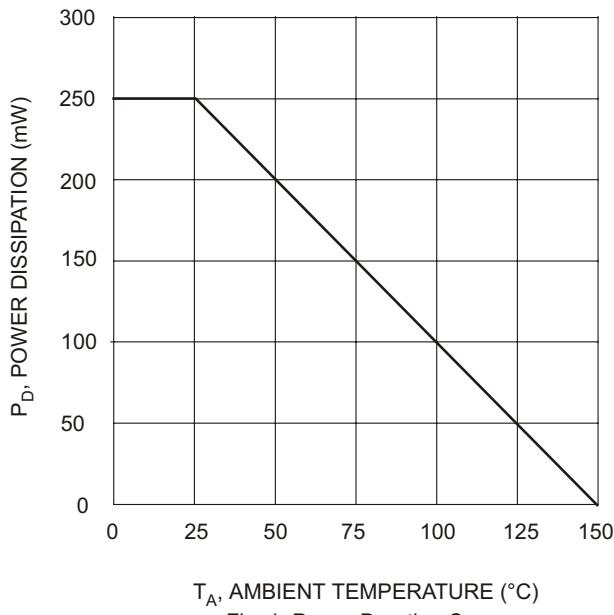


Fig. 1 Power Derating Curve

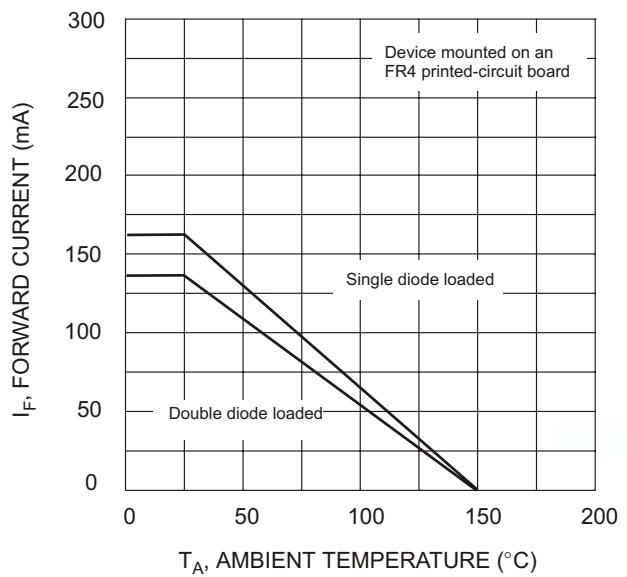


Fig. 2 Current Derating Curve

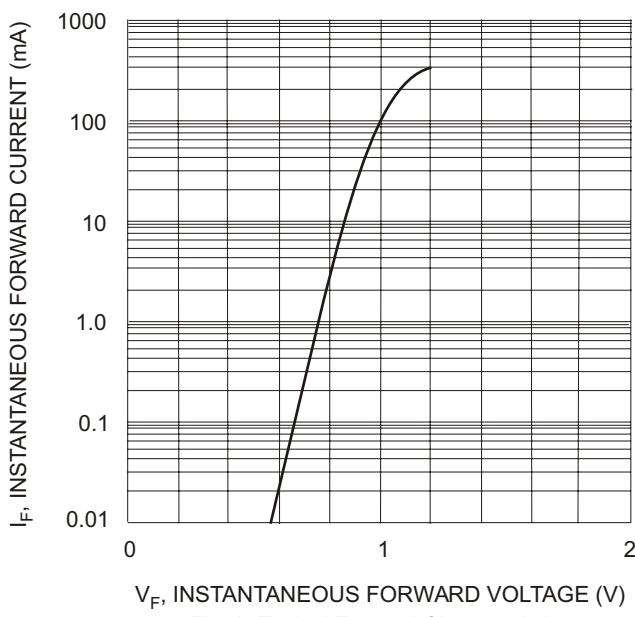


Fig. 3 Typical Forward Characteristics

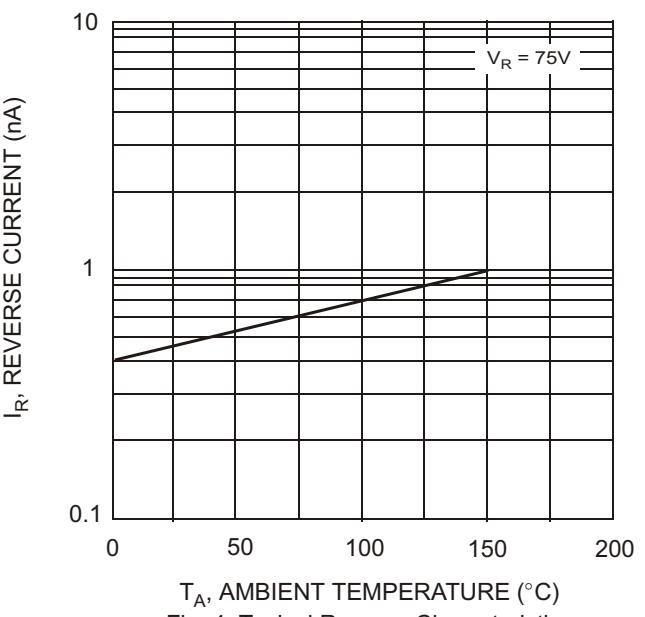
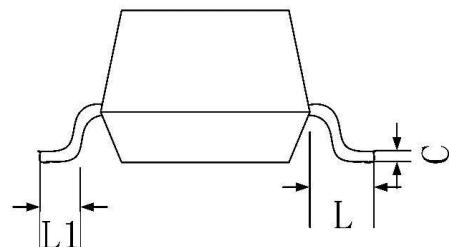
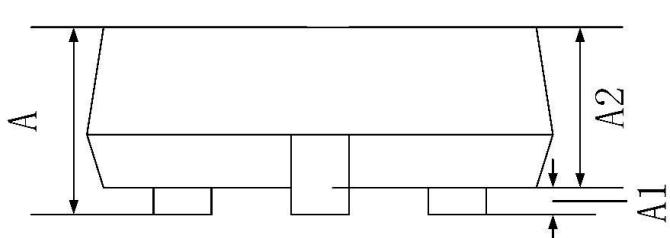
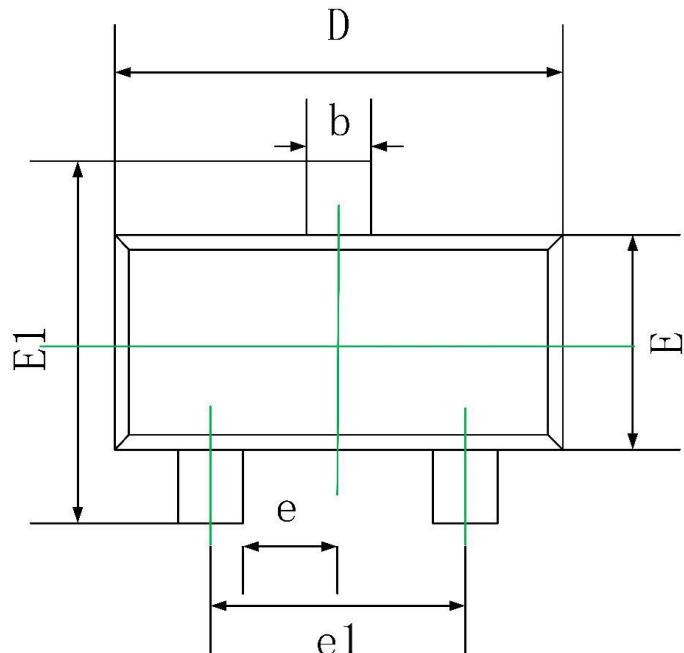


Fig. 4 Typical Reverse Characteristics

SOT-23 Package Information


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020